**Vishay Semiconductors** 

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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	8 A				
V <sub>R</sub>	1200 V				
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.95 V				
t <sub>rr</sub> typ.	42 ns				
T <sub>J</sub> max.	175 °C				
Package	2L TO-220AC				
Circuit configuration	Single				

### FEATURES

- Ultrafast and soft recovery time
- Optimized forward voltage drop
- Polyimide passivation
- 175 °C maximum operating junction temperature
- Rugged design
- Good thermal performance
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Ultrafast recovery rectifiers designed with optimized forward voltage drop, ultrafast recovery time, and soft recovery. Polyimide passivated with a planar structure and platinum doped life time control guarantee ruggedness, reliability, and offer a solid value for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery chargers, inverters for solar inverters or as freewheeling diodes in motor drives.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V <sub>RRM</sub>		1200	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 140 °C, D = 0.50	8				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 10 ms, sine wave	80	А			
Repetitive peak forward current	I <sub>FRM</sub>		16				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MA					
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	$V_{BR}, V_R = 200 \ \mu A$		-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.05	2.55	V	
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	1.95	2.37	]	
Deveras laskage overent	I <sub>R</sub>	$V_R = V_R$ rated	-	-	55		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μA 10	
Junction capacitance	CT	V <sub>R</sub> = 200 V		8	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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 1
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 1.0 \text{ A}$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{A}, V_R = 30 \text{ V}$		42	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	144	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 100 A/μs V <sub>B</sub> = 390 V	-	204	-		
Book receiver aurrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	5	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	7.2	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	370	-	nC	
		T <sub>J</sub> = 125 °C		-	745	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	1.25	1.5			
Thermal resistance, junction to case	R <sub>thJA</sub>	Typical socket mount	-	54	60	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.18	0.4			
Weight			-	0.2	-	g		
weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style 2L TO-220AC	8ETU12					

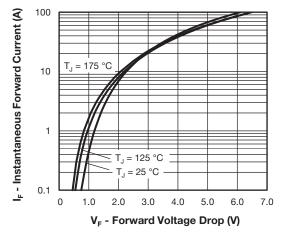


Fig. 1 - Typical Forward Voltage Drop Characteristics

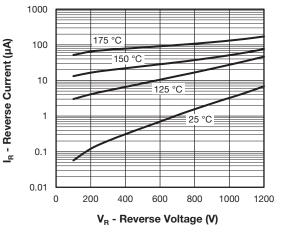


Fig. 2 - Typical Values of Reverse Current vs. **Reverse Voltage** 

## **VS-8ETU12-M3**





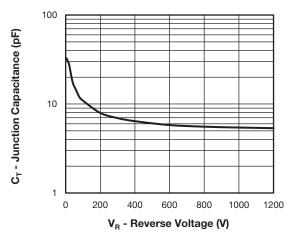


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

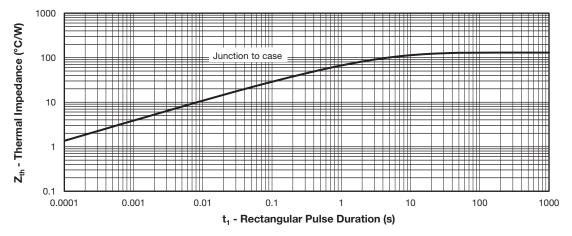


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

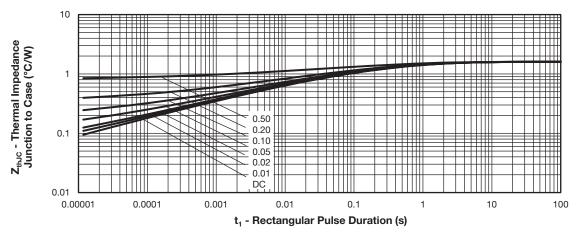
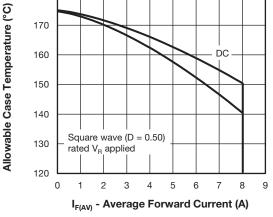
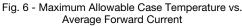


Fig. 5 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

### **Vishay Semiconductors**







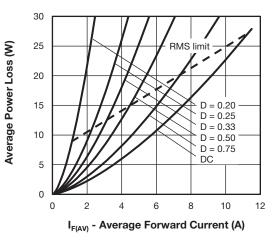


Fig. 7 - Forward Power Loss Characteristics

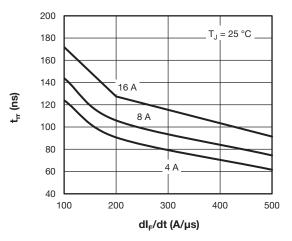


Fig. 8 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

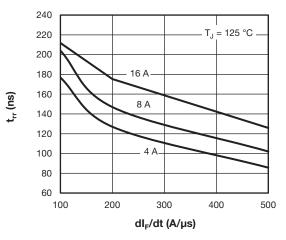


Fig. 9 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

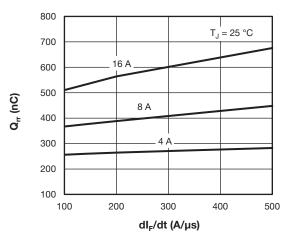


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

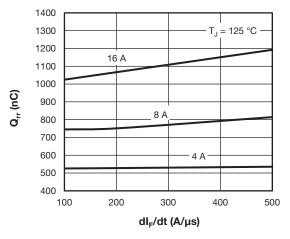


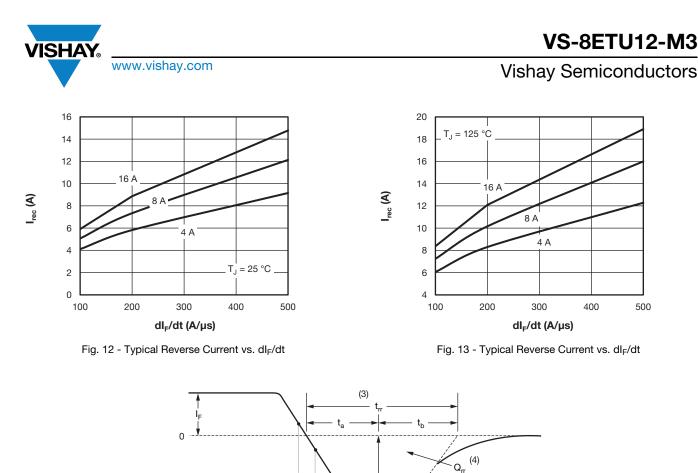
Fig. 11 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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4

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(2) IRRM

Fig. 14 - Reverse Recovery Waveform and Definitions

(1) di<sub>F</sub>/dt

(1) di<sub>F</sub>/dt - rate of change of current

(2) I<sub>RRM</sub> - peak reverse recovery current (3)  $\mathrm{t}_{\mathrm{rr}}$  - reverse recovery time measured

from zero crossing point of negative

going  ${\rm I}_{\rm F}$  to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.

through zero crossing

0.5 I<sub>RRM</sub> di<sub>(rec)M</sub>/dt (5)

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$ 

(5)  $di_{(rec)M}/dt$  - peak rate of change of

current during t<sub>b</sub> portion of t<sub>rr</sub>

 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ 

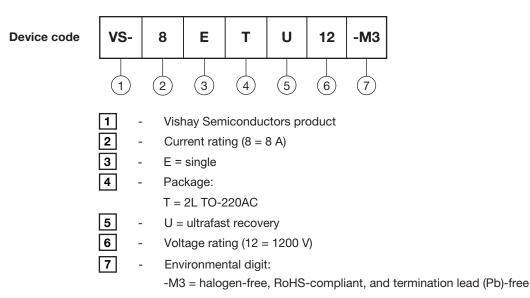
0.75 I<sub>RRM</sub>

and  $I_{\text{RRM}}$ 





### **ORDERING INFORMATION TABLE**



**ORDERING INFORMATION** (Example) PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION VS-8ETU12-M3 1000 50 Antistatic plastic tube

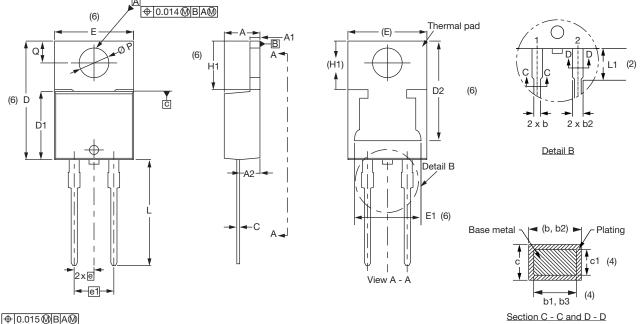
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391				

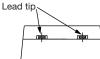


**Vishay Semiconductors** 

# 2L TO-220AC

#### **DIMENSIONS** in millimeters and inches





SYMBOL	MILLIN	MILLIMETERS		INCHES		
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

Conforms to JEDEC<sup>®</sup> outline TO-220AC

SYMBOL	MILLIN	MILLIMETERS		INCHES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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1

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